





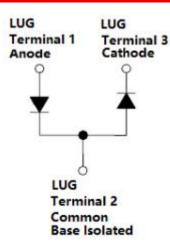
## 203DMQ080/203DMQ100 SCHOTTKY RECTIFIER



#### **Features**

- 175℃ T<sub>J</sub> operation
- · Center tap module
- High purity, high temperature epoxy encapsulation for
- · enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Applications**

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	80	203DMQ080	V
DC Blocking Voltage	VR		100	203DMQ100	·
Average Rectified Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =110°C,	100(Per Leg)		А
Average Nectified Forward Current		rectangular wave form	200(Per Device)		
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse		2520	Α
Non-Repetitive Avalanche Energy(Peg Leg)	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =1A,L=30mH	15		mJ
Repetitive Avalanche Current (Peg Leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> =1.5×V <sub>R</sub> typical	1		А

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  - http://www.smc-diodes.com sales@ smc-diodes.com •









## **Electrical Characteristics:**

Characteristics	Symbol Condition		Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 100A, Pulse, T <sub>J</sub> = 25 °C @ 200A, Pulse, T <sub>J</sub> = 25 °C	0.80 0.88	0.86 1.03	V
	V <sub>F2</sub>	@ 100A, Pulse, T <sub>J</sub> = 125 °C @ 200A, Pulse, T <sub>J</sub> = 125 °C	0.70 0.77	0.75 0.84	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25  ^{\circ}\text{C}$	0.6	3000	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R_i} T_J = 125  ^{\circ}\text{C}$	0.2	40	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2670	3000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

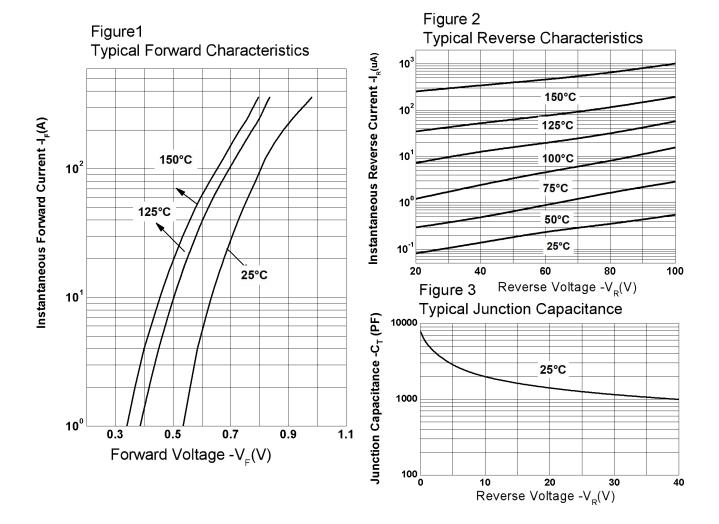
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.30		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.15		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.05		°C/W
Mounting Torque	т		Mounting Torque	24(min) 35(max)	Kg-cm
Wounting Forque	$T_M$	-	Terminal Torque	35(min) 46(max)	Kg-ciii
Approximate Weight	wt	-	110		g
Case Style	PRM4 Isolated				







## **Ratings and Characteristics Curves**



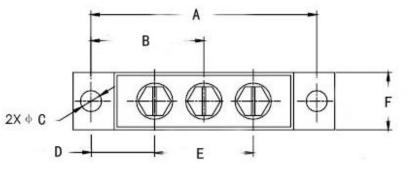


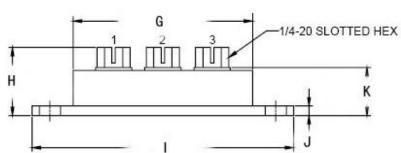






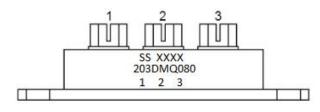
## **Mechanical Dimensions PRM4 Isolated(Millimeters/Inches)**





SYMBOL	Millimeters		Inches	
STIVIBUL	Min.	Max.	Min.	Max.
А	78.74	81.28	3.100	3.200
В	37.47	42.55	1.475	1.675
С	6.89	7.69	0.271	0.303
D	19.51	24.59	0.768	0.968
E	33.02	38.10	1.300	1.500
F	17.78	20.32	0.700	0.800
G	60.96	64.77	2.400	2.550
Н	17.56	23.55	0.691	0.927
I	90.17	92.71	3.550	3.650
J	3.02	3.68	0.119	0.145
K	15.75	17.50	0.620	0.689

## **Marking Diagram**



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**Ordering Information** 

Device	Package	Shipping	
03DMQ SERIES	PRM4 Isolated (Pb-Free)	9 pcs/box	

Where XXXX is YYWW

203DMQ080 = Part name SS YY = SS = Year WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0









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